# NSN 5962-00-434-3046

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#### **Body Outside Diameter:**

Between 0.335 inches and 0.370 inches

#### **Body Height:**

Between 0.165 inches and 0.180 inches

## **Maximum Power Dissipation Rating:**

500.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and hermetically sealed and high gain and negative outputs and positive outputs and low power

#### **Inclosure Material:**

Glass and metal

#### **Inclosure Configuration:**

# Can

**Input Circuit Pattern:** 

2 input

#### **Case Outline Source And Designator:**

T0-99 joint electron device engineering council

#### **Terminal Surface Treatment:**

Gold

#### Voltage Rating And Type Per Characteristic:

22.0 volts power source

#### **Time Rating Per Chacteristic:**

300.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Rom

#### **Precious Material And Location:**

Terminal surface gold

#### **Precious Material:**

Gold

### **Test Data Document:**

30221-44a340319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

8 pin

### Shelf Life:

N/a

#### Unit Of Measure:

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- **Demilitarization:**
- Yes demil/mli

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